# NSN 5961-00-350-8230

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# Inclosure Material:

Metal

# **Overall Length:**

Between 0.380 inches and 0.420 inches

# **Overall Height:**

Between 0.560 inches and 0.620 inches

## **Overall Width:**

Between 0.140 inches and 0.160 inches

# Mounting Facility Quantity:

1

# Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 3.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

2.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

3 uninsulated wire lead

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

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